

# 74AUP1T58

Low-power configurable gate with voltage-level translator

Rev. 7 — 26 January 2022

Product data sheet

## 1. General description

The 74AUP1T58 is a configurable multiple function gate with level translating, Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{CC}$  or GND. Low threshold Schmitt trigger inputs allow these devices to be driven by 1.8 V logic levels in 3.3 V applications.

This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 2.3 V to 3.6 V. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

## 2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- Low static power consumption;  $I_{CC} = 1.5 \mu\text{A}$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial power-down mode operation
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

## 3. Ordering information

Table 1. Ordering information

| Type number | Package           |        |   | Version  |
|-------------|-------------------|--------|---|----------|
|             | Temperature range | Name   | Description   |          |
| 74AUP1T58GW | -40 °C to +125 °C | TSSOP6 | plastic thin shrink small outline package; 6 leads; body width 1.25 mm                      | SOT363-2 |
| 74AUP1T58GM | -40 °C to +125 °C | XSON6  | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm | SOT886   |
| 74AUP1T58GN | -40 °C to +125 °C | XSON6  | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm       | SOT1115  |
| 74AUP1T58GS | -40 °C to +125 °C | XSON6  | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm       | SOT1202  |

## 4. Marking

Table 2. Marking

| Type number | Marking code [1] |
|-------------|------------------|
| 74AUP1T58GW | a8               |
| 74AUP1T58GM | a8               |
| 74AUP1T58GN | a8               |
| 74AUP1T58GS | a8               |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram

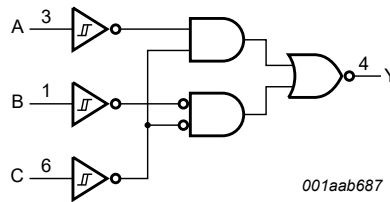


Fig. 1. Logic symbol

## 6. Pinning information

### 6.1. Pinning

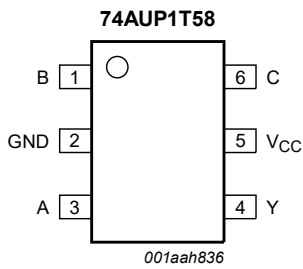


Fig. 2. Pin configuration SOT363-2 (TSSOP6)

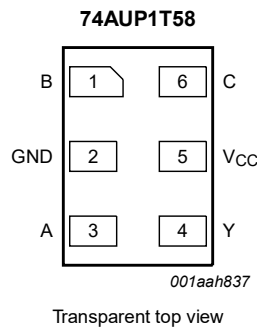


Fig. 3. Pin configuration SOT886 (XSON6)

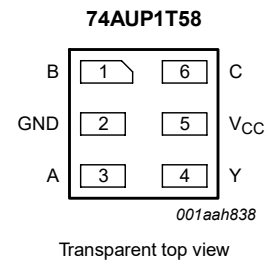


Fig. 4. Pin configuration SOT1115 and SOT1202 (XSON6)

## 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| B               | 1   | data input     |
| GND             | 2   | ground (0 V)   |
| A               | 3   | data input     |
| Y               | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |
| C               | 6   | data input     |

## 7. Functional description

Table 4. Function table

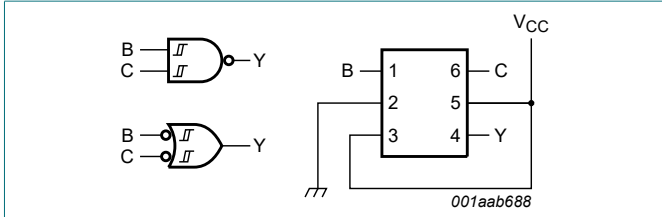
*H = HIGH voltage level; L = LOW voltage level.*

| Input |   |   | Output |
|-------|---|---|--------|
| C     | B | A | Y      |
| L     | L | L | L      |
| L     | L | H | H      |
| L     | H | L | L      |
| L     | H | H | H      |
| H     | L | L | H      |
| H     | L | H | H      |
| H     | H | L | L      |
| H     | H | H | L      |

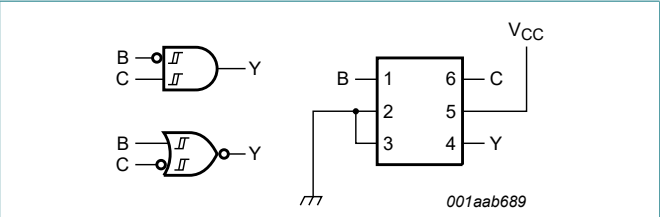
### 7.1. Logic configurations

Table 5. Function selection table

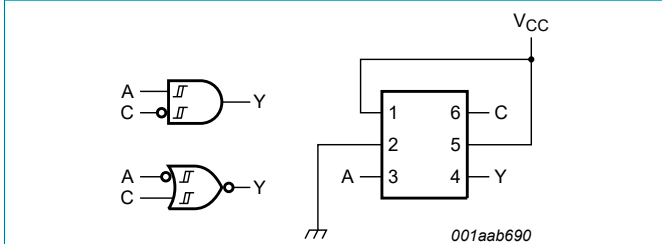
| Logic function                         | Figure  |
|--|---|
| 2-input NAND                           | see <a href="#">Fig. 5</a>                            |
| 2-input NAND with both inputs inverted | see <a href="#">Fig. 8</a>                            |
| 2-input AND with inverted input        | see <a href="#">Fig. 6</a> and <a href="#">Fig. 7</a> |
| 2-input NOR with inverted input        | see <a href="#">Fig. 6</a> and <a href="#">Fig. 7</a> |
| 2-input OR                             | see <a href="#">Fig. 8</a>                            |
| 2-input OR with both inputs inverted   | see <a href="#">Fig. 5</a>                            |
| 2-input XOR                            | see <a href="#">Fig. 9</a>                            |
| Buffer                                 | see <a href="#">Fig. 10</a>                           |
| Inverter                               | see <a href="#">Fig. 11</a>                           |



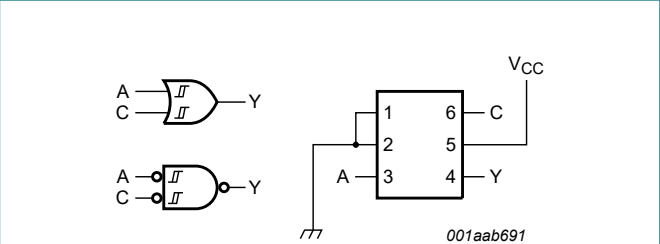
**Fig. 5. 2-input NAND gate or 2-input OR gate with both inputs inverted**



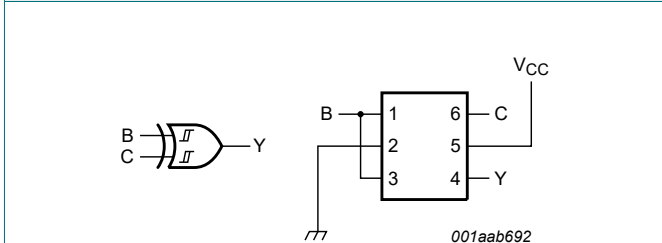
**Fig. 6. 2-input AND gate with input B inverted or 2-input NOR gate with inverted C input**



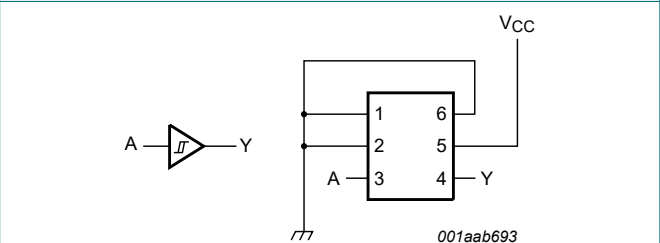
**Fig. 7. 2-input AND gate with input C inverted or 2-input NOR gate with inverted A input**



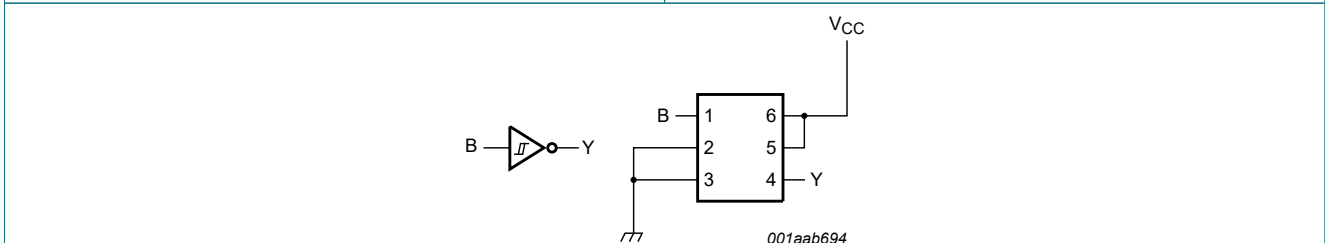
**Fig. 8. 2-input OR gate or 2-input NAND gate with both inputs inverted**



**Fig. 9. 2-input XOR gate**



**Fig. 10. Buffer**



**Fig. 11. Inverter**

## 8. Limiting values

**Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                      | Min  | Max      | Unit |
|-----------|-------------------------|---------------------------------|------|----------|------|
| $V_{CC}$  | supply voltage          |                                 | -0.5 | +4.6     | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                     | -50  | -        | mA   |
| $V_I$     | input voltage           |                                 | -0.5 | +4.6     | V    |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                     | -50  | -        | mA   |
| $V_O$     | output voltage          | Active mode and Power-down mode | -0.5 | +4.6     | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$         | -    | $\pm 20$ | mA   |
| $I_{CC}$  | supply current          |                                 | -    | 50       | mA   |
| $I_{GND}$ | ground current          |                                 | -50  | -        | mA   |
| $T_{stg}$ | storage temperature     |                                 | -65  | +150     | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C   | -    | 250      | mW   |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT363-2 (TSSOP6) package:  $P_{tot}$  derates linearly with 3.7 mW/K above 83 °C.

For SOT886 (XSON6) package:  $P_{tot}$  derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package:  $P_{tot}$  derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package:  $P_{tot}$  derates linearly with 3.3 mW/K above 74 °C.

## 9. Recommended operating conditions

**Table 7. Recommended operating conditions**

| Symbol    | Parameter           | Conditions                      | Min | Max      | Unit |
|-----------|---------------------|---------------------------------|-----|----------|------|
| $V_{CC}$  | supply voltage      |                                 | 2.3 | 3.6      | V    |
| $V_I$     | input voltage       |                                 | 0   | 3.6      | V    |
| $V_O$     | output voltage      | Active mode                     | 0   | $V_{CC}$ | V    |
|           |                     | Power-down mode; $V_{CC} = 0$ V | 0   | 3.6      | V    |
| $T_{amb}$ | ambient temperature |                                 | -40 | +125     | °C   |

## 10. Static characteristics

**Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                         | Parameter                            | Conditions   | Min                   | Typ | Max  | Unit |
|--------------------------------|--------------------------------------|--|-----------------------|-----|------|------|
| <b>T<sub>amb</sub> = 25 °C</b> |                                      |  |                       |     |      |      |
| V <sub>T+</sub>                | positive-going threshold voltage     | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0.60                  | -   | 1.10 | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 0.75                  | -   | 1.16 | V    |
| V <sub>T-</sub>                | negative-going threshold voltage     | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0.35                  | -   | 0.60 | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 0.50                  | -   | 0.85 | V    |
| V <sub>H</sub>                 | hysteresis voltage                   | (V <sub>H</sub> = V <sub>T+</sub> - V <sub>T-</sub> )  |                       |     |      |      |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0.23                  | -   | 0.60 | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 0.25                  | -   | 0.56 | V    |
| V <sub>OH</sub>                | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>  |                       |     |      |      |
|                                |                                      | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V  | V <sub>CC</sub> - 0.1 | -   | -    | V    |
|                                |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V  | 2.05                  | -   | -    | V    |
|                                |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V  | 1.9                   | -   | -    | V    |
|                                |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V  | 2.72                  | -   | -    | V    |
|                                |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V  | 2.6                   | -   | -    | V    |
| V <sub>OL</sub>                | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>  |                       |     |      |      |
|                                |                                      | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V   | -                     | -   | 0.10 | V    |
|                                |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V   | -                     | -   | 0.31 | V    |
|                                |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V   | -                     | -   | 0.44 | V    |
|                                |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V   | -                     | -   | 0.31 | V    |
|                                |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V   | -                     | -   | 0.44 | V    |
| I <sub>I</sub>                 | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                    | -                     | -   | ±0.1 | μA   |
| I <sub>OFF</sub>               | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                           | -                     | -   | ±0.1 | μA   |
| ΔI <sub>OFF</sub>              | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V                  | -                     | -   | ±0.2 | μA   |
| I <sub>CC</sub>                | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V | -                     | -   | 1.2  | μA   |
| C <sub>I</sub>                 | input capacitance                    | V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>                          | -                     | 0.8 | -    | pF   |
| C <sub>O</sub>                 | output capacitance                   | V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V  | -                     | 1.7 | -    | pF   |

## Low-power configurable gate with voltage-level translator

| Symbol                                    | Parameter                            | Conditions  | Min                   | Typ | Max  | Unit |
|---|--------------------------------------|---|-----------------------|-----|------|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b> |                                      |   |                       |     |      |      |
| V <sub>T+</sub>                           | positive-going threshold voltage     | V <sub>CC</sub> = 2.3 V to 2.7 V  | 0.60                  | -   | 1.10 | V    |
|   |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 0.75                  | -   | 1.19 | V    |
| V <sub>T-</sub>                           | negative-going threshold voltage     | V <sub>CC</sub> = 2.3 V to 2.7 V  | 0.35                  | -   | 0.60 | V    |
|   |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 0.50                  | -   | 0.85 | V    |
| V <sub>H</sub>                            | hysteresis voltage                   | (V <sub>H</sub> = V <sub>T+</sub> - V <sub>T-</sub> )   |                       |     |      |      |
|   |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | 0.10                  | -   | 0.60 | V    |
|   |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 0.15                  | -   | 0.56 | V    |
| V <sub>OH</sub>                           | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>   |                       |     |      |      |
|   |                                      | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V   | V <sub>CC</sub> - 0.1 | -   | -    | V    |
|   |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V   | 1.97                  | -   | -    | V    |
|   |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V   | 1.85                  | -   | -    | V    |
|   |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V   | 2.67                  | -   | -    | V    |
|   |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V   | 2.55                  | -   | -    | V    |
| V <sub>OL</sub>                           | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>   |                       |     |      |      |
|   |                                      | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V  | -                     | -   | 0.1  | V    |
|   |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V  | -                     | -   | 0.33 | V    |
|   |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V  | -                     | -   | 0.45 | V    |
|   |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V  | -                     | -   | 0.33 | V    |
|   |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V  | -                     | -   | 0.45 | V    |
| I <sub>I</sub>                            | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                       | -                     | -   | ±0.5 | μA   |
| I <sub>OFF</sub>                          | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                              | -                     | -   | ±0.5 | μA   |
| ΔI <sub>OFF</sub>                         | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V to 0.2 V                  | -                     | -   | ±0.5 | μA   |
| I <sub>CC</sub>                           | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 2.3 V to 3.6 V | -                     | -   | 1.5  | μA   |
| ΔI <sub>CC</sub>                          | additional supply current            | V <sub>CC</sub> = 2.3 V to 2.7 V; I <sub>O</sub> = 0 A [1]  | -                     | -   | 4    | μA   |
|   |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A [2]  | -                     | -   | 12   | μA   |

## Low-power configurable gate with voltage-level translator

| Symbol                                     | Parameter                            | Conditions   | Min                    | Typ | Max   | Unit |
|--|--------------------------------------|--|------------------------|-----|-------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                      |  |                        |     |       |      |
| V <sub>T+</sub>                            | positive-going threshold voltage     | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0.60                   | -   | 1.10  | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 0.75                   | -   | 1.19  | V    |
| V <sub>T-</sub>                            | negative-going threshold voltage     | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0.33                   | -   | 0.64  | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 0.46                   | -   | 0.85  | V    |
| V <sub>H</sub>                             | hysteresis voltage                   | (V <sub>H</sub> = V <sub>T+</sub> - V <sub>T-</sub> )  |                        |     |       |      |
|  |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0.10                   | -   | 0.60  | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 0.15                   | -   | 0.56  | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage            | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>  |                        |     |       |      |
|  |                                      | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V  | V <sub>CC</sub> - 0.11 | -   | -     | V    |
|  |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V  | 1.77                   | -   | -     | V    |
|  |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V  | 1.67                   | -   | -     | V    |
|  |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V  | 2.40                   | -   | -     | V    |
|  |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V  | 2.30                   | -   | -     | V    |
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>  |                        |     |       |      |
|  |                                      | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.3 V to 3.6 V   | -                      | -   | 0.11  | V    |
|  |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V   | -                      | -   | 0.36  | V    |
|  |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V   | -                      | -   | 0.50  | V    |
|  |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V   | -                      | -   | 0.36  | V    |
|  |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V   | -                      | -   | 0.50  | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                    | -                      | -   | ±0.75 | μA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                           | -                      | -   | ±0.75 | μA   |
| ΔI <sub>OFF</sub>                          | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.75 | μA   |
| I <sub>CC</sub>                            | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 2.3 V to 3.6 V | -                      | -   | 3.5   | μA   |
| ΔI <sub>CC</sub>                           | additional supply current            | V <sub>CC</sub> = 2.3 V to 2.7 V; I <sub>O</sub> = 0 A [1]                                       | -                      | -   | 7     | μA   |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A [2]                                       | -                      | -   | 22    | μA   |

[1] One input at 0.3 V or 1.1 V, other input at V<sub>CC</sub> or GND.

[2] One input at 0.45 V or 1.2 V, other input at V<sub>CC</sub> or GND.

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 13.

| Symbol   | Parameter         | Conditions                    | 25 °C |         |     | -40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|--|-------------------|-------------------------------|-------|---------|-----|------------------|------|-------------------|------|------|
|  |                   |                               | Min   | Typ [1] | Max | Min              | Max  | Min               | Max  |      |
| <b>V<sub>CC</sub> = 2.3 V to 2.7 V; V<sub>I</sub> = 1.65 V to 1.95 V</b> |                   |                               |       |         |     |                  |      |                   |      |      |
| t <sub>pd</sub>  | propagation delay | A, B, C to Y; see Fig. 12 [2] |       |         |     |                  |      |                   |      |      |
|  |                   | C <sub>L</sub> = 5 pF         | 2.1   | 3.6     | 5.6 | 0.5              | 6.8  | 0.5               | 7.5  | ns   |
|  |                   | C <sub>L</sub> = 10 pF        | 2.6   | 4.1     | 6.2 | 1.0              | 7.9  | 1.0               | 8.7  | ns   |
|  |                   | C <sub>L</sub> = 15 pF        | 3.0   | 4.6     | 6.8 | 1.0              | 8.7  | 1.0               | 9.6  | ns   |
|  |                   | C <sub>L</sub> = 30 pF        | 4.0   | 5.8     | 8.1 | 1.5              | 10.8 | 1.5               | 11.9 | ns   |
| <b>V<sub>CC</sub> = 2.3 V to 2.7 V; V<sub>I</sub> = 2.3 V to 2.7 V</b>   |                   |                               |       |         |     |                  |      |                   |      |      |
| t <sub>pd</sub>  | propagation delay | A, B, C to Y; see Fig. 12 [2] |       |         |     |                  |      |                   |      |      |
|  |                   | C <sub>L</sub> = 5 pF         | 1.7   | 3.4     | 5.5 | 0.5              | 6.0  | 0.5               | 6.6  | ns   |
|  |                   | C <sub>L</sub> = 10 pF        | 2.2   | 4.0     | 6.2 | 1.0              | 7.1  | 1.0               | 7.9  | ns   |
|  |                   | C <sub>L</sub> = 15 pF        | 2.6   | 4.5     | 6.8 | 1.0              | 7.9  | 1.0               | 8.7  | ns   |
|  |                   | C <sub>L</sub> = 30 pF        | 3.5   | 5.6     | 8.1 | 1.5              | 10.0 | 1.5               | 11.0 | ns   |
| <b>V<sub>CC</sub> = 2.3 V to 2.7 V; V<sub>I</sub> = 3.0 V to 3.6 V</b>   |                   |                               |       |         |     |                  |      |                   |      |      |
| t <sub>pd</sub>  | propagation delay | A, B, C to Y; see Fig. 12 [2] |       |         |     |                  |      |                   |      |      |
|  |                   | C <sub>L</sub> = 5 pF         | 1.4   | 3.2     | 5.1 | 0.5              | 5.5  | 0.5               | 6.1  | ns   |
|  |                   | C <sub>L</sub> = 10 pF        | 1.9   | 3.7     | 5.8 | 1.0              | 6.5  | 1.0               | 7.2  | ns   |
|  |                   | C <sub>L</sub> = 15 pF        | 2.2   | 4.2     | 6.3 | 1.0              | 7.4  | 1.0               | 8.2  | ns   |
|  |                   | C <sub>L</sub> = 30 pF        | 3.2   | 5.4     | 7.7 | 1.5              | 9.5  | 1.5               | 10.5 | ns   |
| <b>V<sub>CC</sub> = 3.0 V to 3.6 V; V<sub>I</sub> = 1.65 V to 1.95 V</b> |                   |                               |       |         |     |                  |      |                   |      |      |
| t <sub>pd</sub>  | propagation delay | A, B, C to Y; see Fig. 12 [2] |       |         |     |                  |      |                   |      |      |
|  |                   | C <sub>L</sub> = 5 pF         | 2.0   | 2.9     | 4.0 | 0.5              | 8.0  | 0.5               | 8.8  | ns   |
|  |                   | C <sub>L</sub> = 10 pF        | 2.4   | 3.5     | 4.7 | 1.0              | 8.5  | 1.0               | 9.4  | ns   |
|  |                   | C <sub>L</sub> = 15 pF        | 2.8   | 3.9     | 5.3 | 1.0              | 9.1  | 1.0               | 10.1 | ns   |
|  |                   | C <sub>L</sub> = 30 pF        | 3.6   | 5.1     | 6.7 | 1.5              | 9.8  | 1.5               | 10.8 | ns   |
| <b>V<sub>CC</sub> = 3.0 V to 3.6 V; V<sub>I</sub> = 2.3 V to 2.7 V</b>   |                   |                               |       |         |     |                  |      |                   |      |      |
| t <sub>pd</sub>  | propagation delay | A, B, C to Y; see Fig. 12 [2] |       |         |     |                  |      |                   |      |      |
|  |                   | C <sub>L</sub> = 5 pF         | 1.6   | 2.8     | 4.4 | 0.5              | 5.3  | 0.5               | 5.9  | ns   |
|  |                   | C <sub>L</sub> = 10 pF        | 2.1   | 3.4     | 5.1 | 1.0              | 6.1  | 1.0               | 6.8  | ns   |
|  |                   | C <sub>L</sub> = 15 pF        | 2.4   | 3.9     | 5.6 | 1.0              | 6.8  | 1.0               | 7.5  | ns   |
|  |                   | C <sub>L</sub> = 30 pF        | 3.4   | 5.0     | 7.0 | 1.5              | 8.5  | 1.5               | 9.4  | ns   |
| <b>V<sub>CC</sub> = 3.0 V to 3.6 V; V<sub>I</sub> = 3.0 V to 3.6 V</b>   |                   |                               |       |         |     |                  |      |                   |      |      |
| t <sub>pd</sub>  | propagation delay | A, B, C to Y; see Fig. 12 [2] |       |         |     |                  |      |                   |      |      |
|  |                   | C <sub>L</sub> = 5 pF         | 1.3   | 2.8     | 4.4 | 0.5              | 4.7  | 0.5               | 5.2  | ns   |
|  |                   | C <sub>L</sub> = 10 pF        | 1.7   | 3.3     | 5.1 | 1.0              | 5.7  | 1.0               | 6.3  | ns   |
|  |                   | C <sub>L</sub> = 15 pF        | 2.1   | 3.8     | 5.7 | 1.0              | 6.2  | 1.0               | 6.9  | ns   |
|  |                   | C <sub>L</sub> = 30 pF        | 3.1   | 4.9     | 7.0 | 1.5              | 7.8  | 1.5               | 8.6  | ns   |

Low-power configurable gate with voltage-level translator

| Symbol                         | Parameter                     | Conditions  | 25 °C |         |     | -40 °C to +85 °C |     | -40 °C to +125 °C |     | Unit |
|--------------------------------|-------------------------------|---|-------|---------|-----|------------------|-----|-------------------|-----|------|
|                                |                               |   | Min   | Typ [1] | Max | Min              | Max | Min               | Max |      |
| <b>T<sub>amb</sub> = 25 °C</b> |                               |   |       |         |     |                  |     |                   |     |      |
| C <sub>PD</sub>                | power dissipation capacitance | f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> [3] |       |         |     |                  |     |                   |     |      |
|                                |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                                    | -     | 3.6     | -   | -                | -   | -                 | -   | pF   |
|                                |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                    | -     | 4.3     | -   | -                | -   | -                 | -   | pF   |

- [1] All typical values are measured at nominal V<sub>CC</sub>.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = output load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

11.1. Waveforms and test circuit

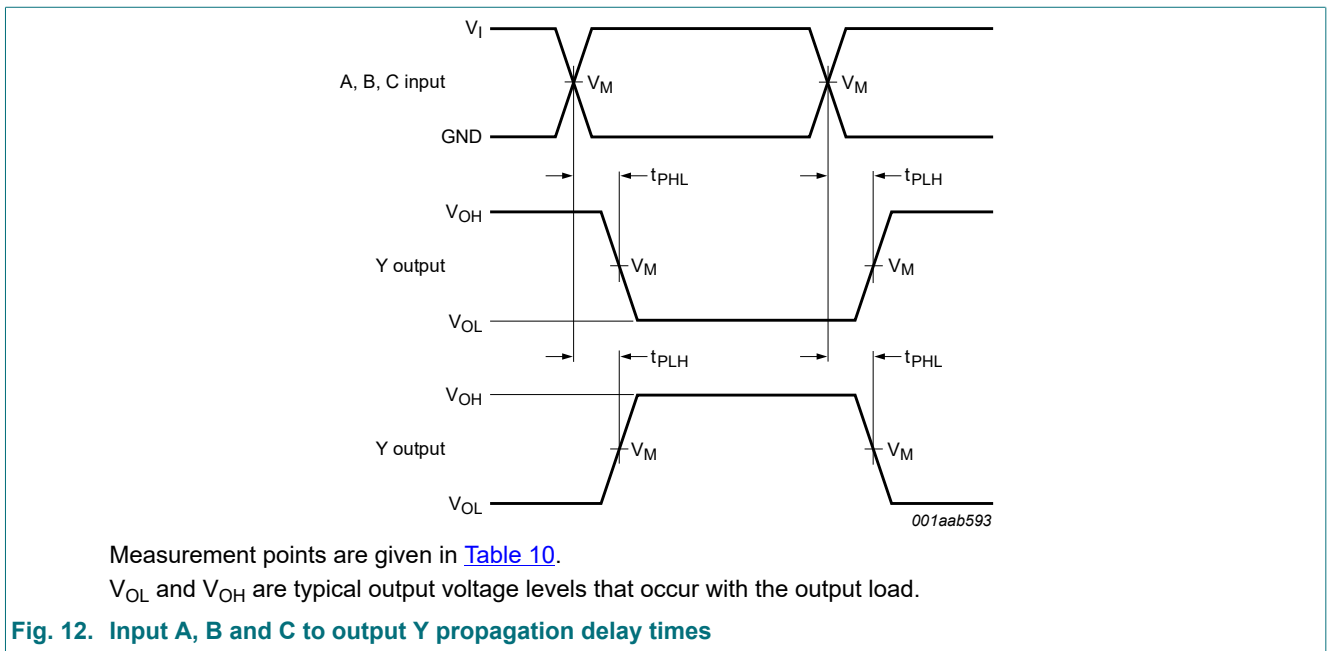
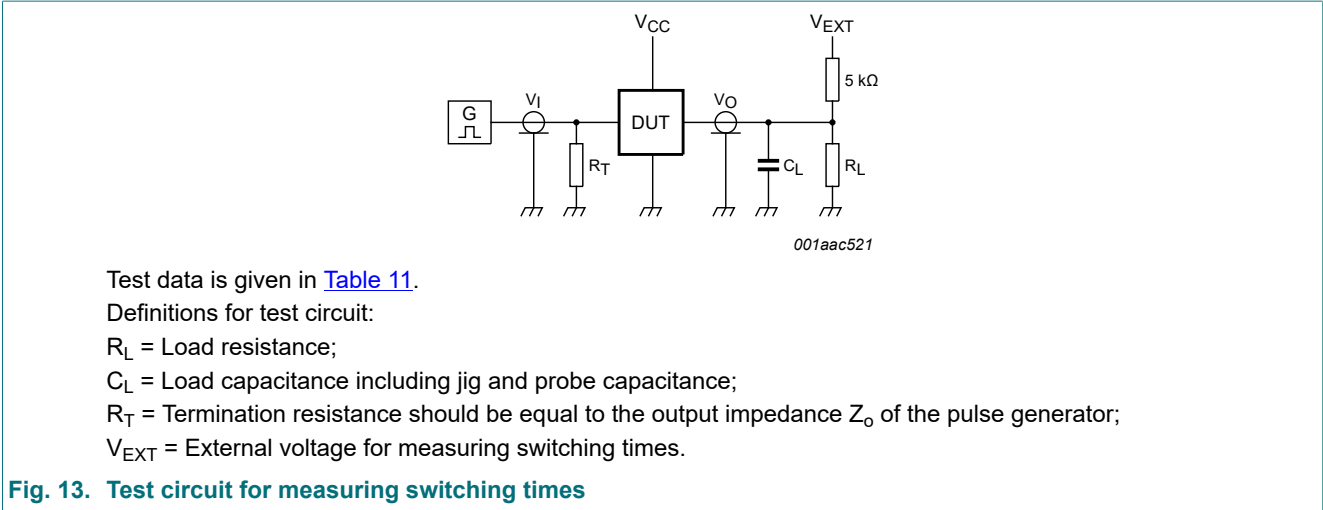


Table 10. Measurement points

| Supply voltage  | Output                | Input                |                 |                                 |
|-----------------|-----------------------|----------------------|-----------------|---------------------------------|
| V <sub>CC</sub> | V <sub>M</sub>        | V <sub>M</sub>       | V <sub>I</sub>  | t <sub>r</sub> = t <sub>f</sub> |
| 2.3 V to 3.6 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>I</sub> | 1.65 V to 3.6 V | ≤ 3.0 ns                        |

Low-power configurable gate with voltage-level translator



**Fig. 13. Test circuit for measuring switching times**

**Table 11. Test data**

| Supply voltage | Load                         |              | $V_{EXT}$             |                       |                       |
|----------------|------------------------------|--------------|-----------------------|-----------------------|-----------------------|
| $V_{CC}$       | $C_L$                        | $R_L$ [1]    | $t_{PLH}$ , $t_{PHL}$ | $t_{PZH}$ , $t_{PHZ}$ | $t_{PZL}$ , $t_{PLZ}$ |
| 2.3 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open                  | GND                   | $2 \times V_{CC}$     |

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ .  
 For measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

## 12. Package outline

TSSOP6: plastic thin shrink small outline package; 6 leads; body width 1.25 mm

SOT363-2

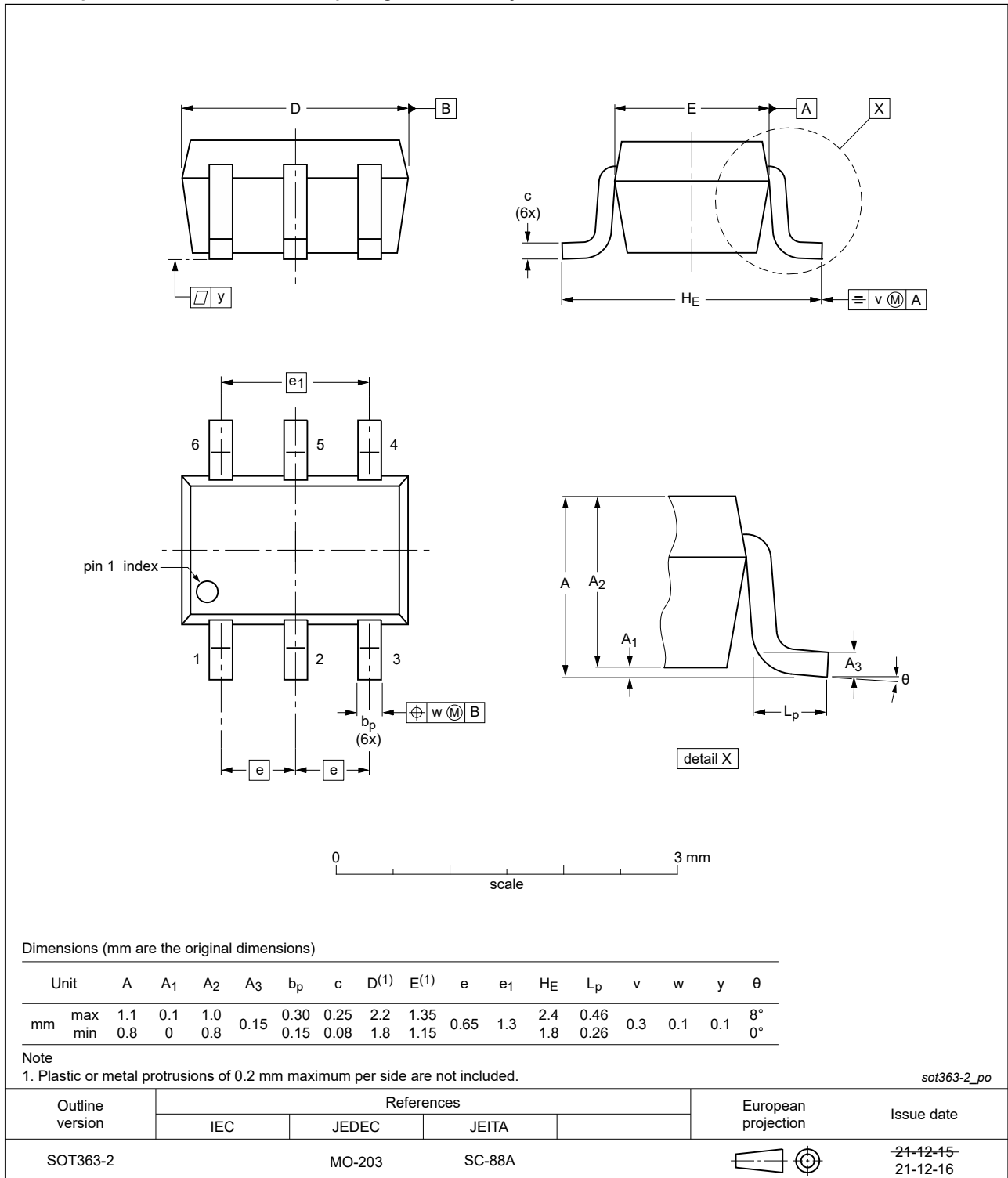


Fig. 14. Package outline SOT363-2 (TSSOP6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

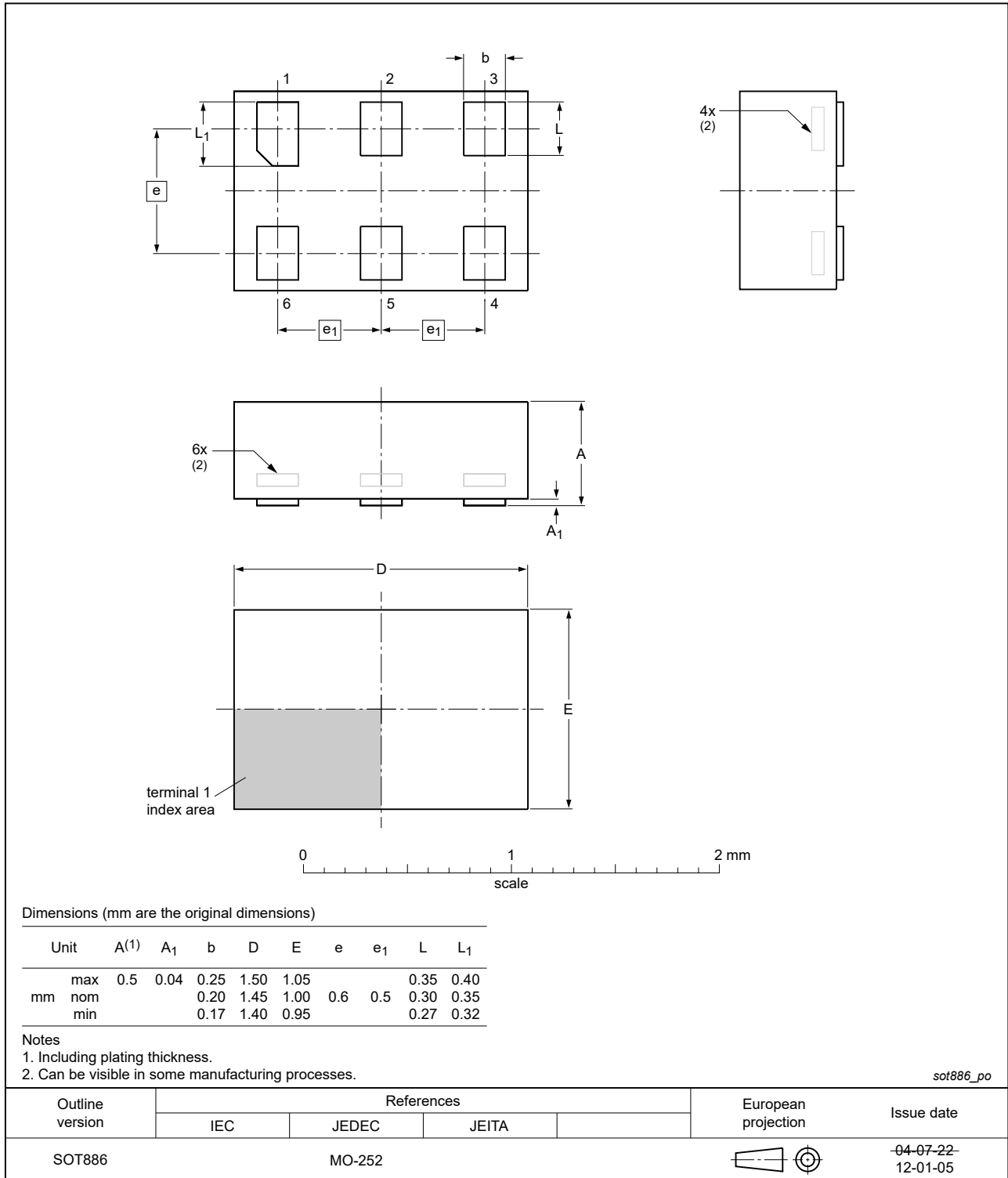


Fig. 15. Package outline SOT886 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115

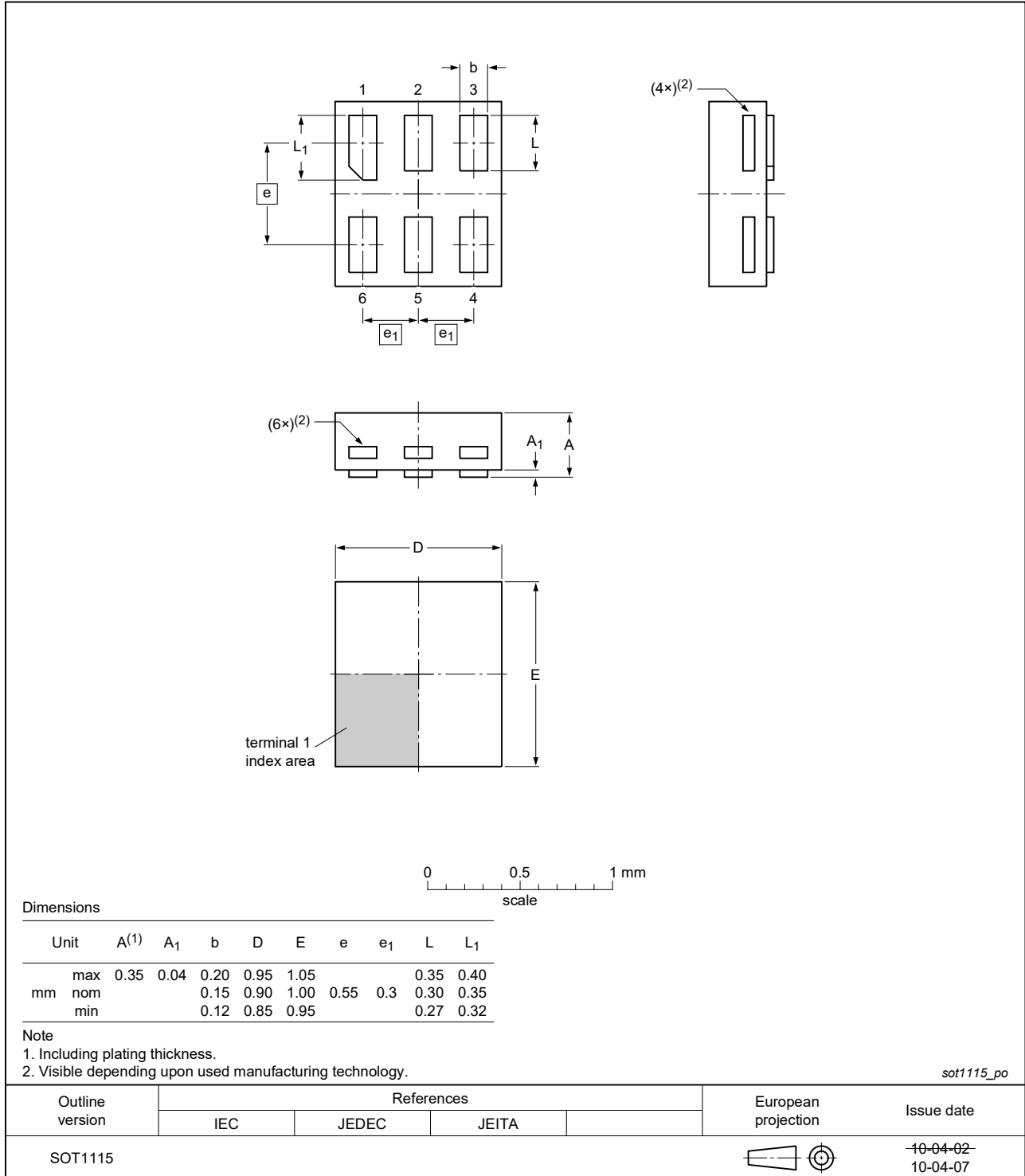


Fig. 16. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202

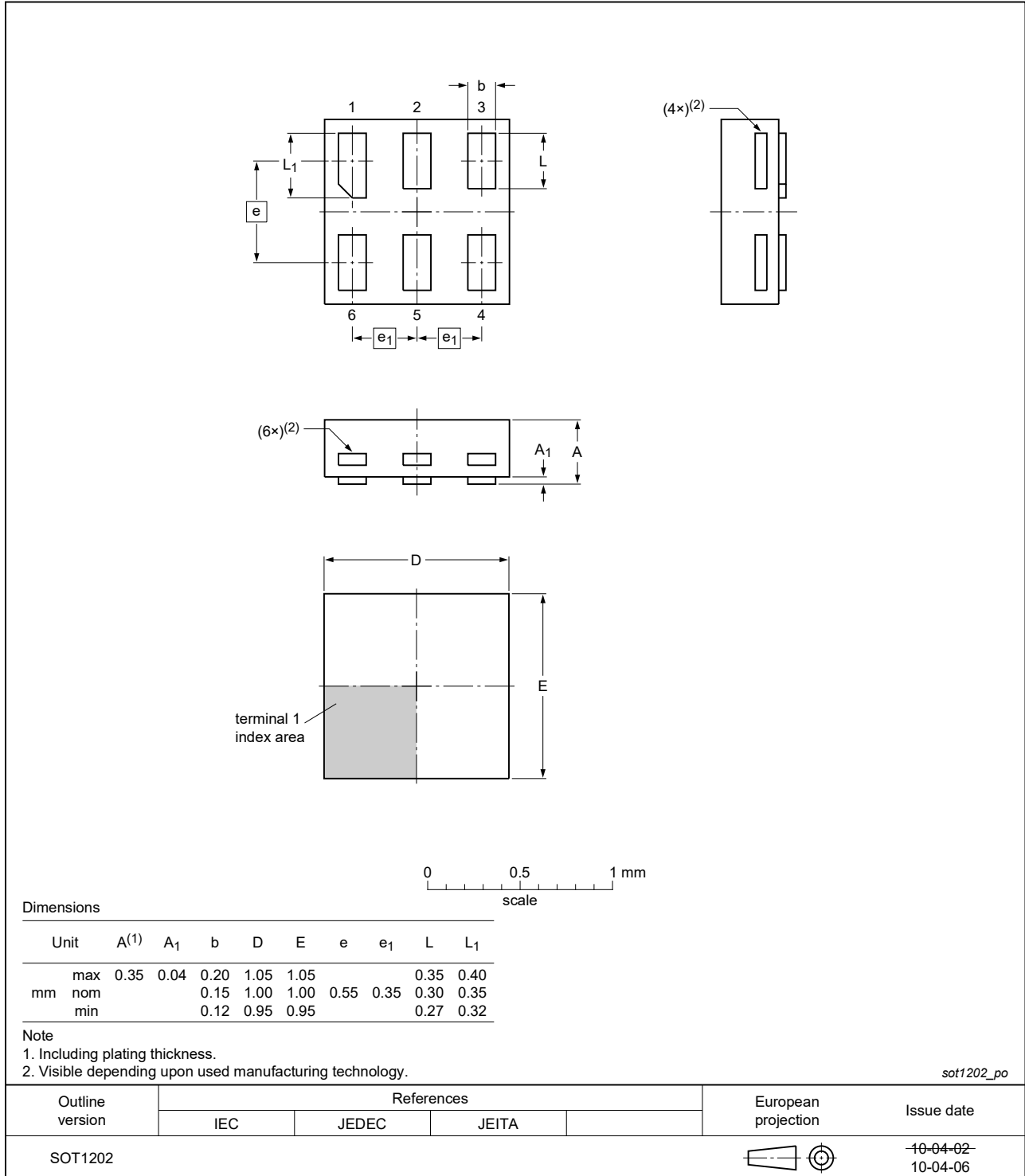


Fig. 17. Package outline SOT1202 (XSON6)

## 13. Abbreviations

Table 12. Abbreviations

| Acronym | Description                             |
|---------|---|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |

## 14. Revision history

Table 13. Revision history

| Document ID    | Release date   | Data sheet status  | Change notice | Supersedes    |
|----------------|--|--------------------|---------------|---------------|
| 74AUP1T58 v.7  | 20220126   | Product data sheet | -             | 74AUP1T58 v.6 |
| Modifications: | <ul style="list-style-type: none"> <li>Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6).</li> </ul>   |                    |               |               |
| 74AUP1T58 v.6  | 20210602   | Product data sheet | -             | 74AUP1T58 v.5 |
| Modifications: | <ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74AUP1T58GF (SOT891 / XSON6) removed.</li> <li><a href="#">Section 1</a> and <a href="#">Section 2</a> updated.</li> <li><a href="#">Section 8</a>: Derating values for <math>P_{tot}</math> total power dissipation updated.</li> </ul> |                    |               |               |
| 74AUP1T58 v.5  | 20120815   | Product data sheet | -             | 74AUP1T58 v.4 |
| Modifications: | <ul style="list-style-type: none"> <li>Package outline drawing of SOT886 (<a href="#">Fig. 15</a>) modified.</li> </ul>  |                    |               |               |
| 74AUP1T58 v.4  | 20111128   | Product data sheet | -             | 74AUP1T58 v.3 |
| 74AUP1T58 v.3  | 20101018   | Product data sheet | -             | 74AUP1T58 v.2 |
| 74AUP1T58 v.2  | 20090929   | Product data sheet | -             | 74AUP1T58 v.1 |
| 74AUP1T58 v.1  | 20080306   | Product data sheet | -             | -             |

## 15. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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